

# THE AH3574 IS <u>NOT</u> RECOMMENDED FOR NEW DESIGNS. PLEASE USE THE AH3524.

AH3574



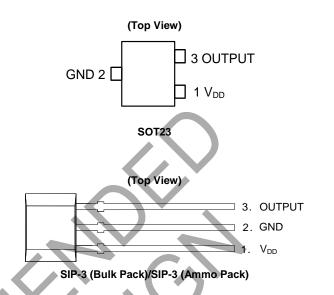
# HIGH-VOLTAGE HIGH-SENSITIVITY HALL-EFFECT OMNIPOLAR SWITCH

### **Description**

The AH3574 is a high-voltage high-sensitivity Hall-effect Omnipolar switch IC designed for proximity, position and level sensing in consumer home appliances, office equipment, smart home to industrial applications. To support the wide range of the demanding applications, the design has been optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3574 provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

The single open-drain output can be switched on with South or North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (BoP) the output is switched on (pulled low) and is held on until magnetic flux density B is lower than the release point (BRP).

### **Pin Assignments**



#### **Features**

- Omnipolar Operation
- High Sensitivity: Bop and BRP of ±40G and ±25G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +125°C Operating Temperature
- ESD: HBM > 6kV
- Industry Standard SOT23, SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

### **Applications**

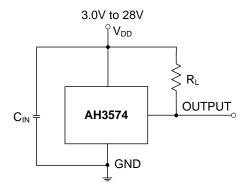
- Position and proximity sensing in consumer home appliances, building automation, office equipment and industrial applications
- Open and close detection
- Position detection
- Level detection
- Flow meters
- Contactless switches

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



## **Typical Applications Circuit**



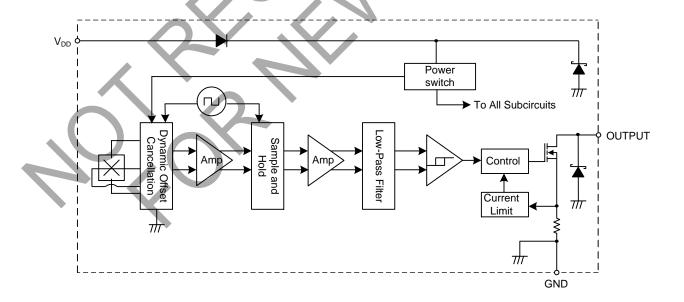
Note: 4. C<sub>IN</sub> is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF to 100nF. R<sub>L</sub> is the pullup resistor.

### **Pin Descriptions**

Packages: SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	V <sub>DD</sub>	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

### **Functional Block Diagram**





### Absolute Maximum Ratings (Notes 5 & 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
$V_{DD}$	Supply Voltage (Note 6)	32	V		
V <sub>DDR</sub>	Reverse Supply Voltage (Note 6)		-32	V	
Vout_max	Output Off Voltage (Note 6)		32	V	
Іоит	Continuous Output Current		60	mA	
lout_r	Reverse Output Current	-50 m/			
В	Magnetic Flux Density		Unlimited		
PD	Package Power Dissipation	SIP-3 (Ammo Pack) SIP-3 (Bulk Pack)	550	mW	
		SOT23	230		
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature	+150	°C		
ESD HBM	Electros Static Discharge Withstand - Human Body Mod	el (HBM)	6	kV	

Notes:

- 5. Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.
- 6. The absolute maximum V<sub>DD</sub> of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

#### Recommended Operating Conditions (@TA = -40°C to +125°C, unless otherwise specified.)

Symbol	Parameter	Condition	Rating	Unit
V <sub>DD</sub>	Supply Voltage	Operating	3.0 to 28	V
T <sub>A</sub>	Operating Temperature Range	Operating	-40 to +125	°C

### Electrical Characteristics (Notes 7 & 8) (@TA = -40°C to +125°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vout_on	Output ON Voltage	IOUT = 20mA, B > BOP	_	0.2	0.4	V
ILKG	Output Leakage Current (When output is off)	Vout = 28V, B < BRP, Output off	_	< 0.1	10	μΑ
I <sub>DD</sub>	Supply Current	Output open, T <sub>A</sub> = +25°C	_	3	3.5	mA
טטו	Supply Current	Output open, T <sub>A</sub> = -40°C to +125°C	_	_	4	mA
	Poverse Pottony Current	$V_{DD} = -18V$ , $T_A = -40^{\circ}C$ to $+125^{\circ}C$	_	-0.01	1	mA
I <sub>DD_R</sub>	Reverse Battery Current	$V_{DD} = -28V$ , $T_A = -40^{\circ}C$ to $+125^{\circ}C$	_	-0.01	1.5	mA
tp_on	Device Power-On Time (Startup Time)	V <sub>DD</sub> ≥ 3V, B > B <sub>OP</sub> (Note 7)	_	10	_	μs
fc	Chopping Frequency	_	_	800	_	kHz
tD	Response Time Delay (Time from magnetic threshold reach to the start of the output rise or fall)	(Note 9)	_	3.75	_	μs
tR	Output Rising Time (External pullup resistor R <sub>L</sub> and load capacitance dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	_	0.2	1	μs
t <sub>F</sub>	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	_	0.1	1	μs
locL	Output Current Limit	B > Bop (Note 10)	30		55	mA
Vz	Zener Clamp Voltage	I <sub>DD</sub> = 5mA	28	_	_	V

Notes:

- 7. When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.
- 8. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 9. Guaranteed by design, process control and characterization, Not tested in production.
- 10. The device will limit the output current  $I_{OUT}$  to current limit of  $I_{OCL}$ .



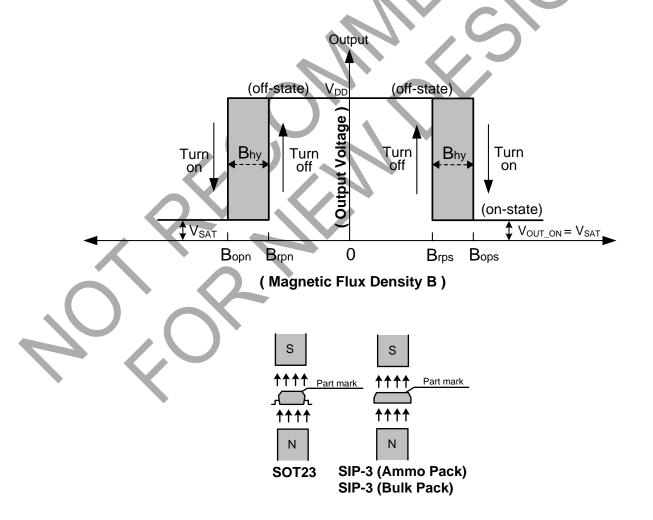
### Magnetic Characteristics (Note 11 & 12) (T<sub>A</sub> = -40°C to +125°C, V<sub>DD</sub> = 3.0V to 28V, unless otherwise specified.)

(1mT=10 Gauss)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Bops		V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	_	40		
(South pole to the part marking side)	On a vetice Deint	T <sub>A</sub> = -40°C to +125°C	20	40	60	
Вори	Operation Point	V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	_	-40	_	
(North pole to the part marking side)		$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-60	-40	-20	
Brps		V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	_	25	_	Gauss
(South pole to the part marking side)	D	T <sub>A</sub> = -40°C to +125°C	10	25	45	Gauss
Brpn	Release Point	V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	<b>/</b> -	-25	_	
(North pole to the part marking side)		T <sub>A</sub> = -40°C to +125°C	-45	-25	-10	
Dong (ID and ID and)	Hystorogia (Note 12)	V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	<b>\</b> -/	15		
BHY ( BOPX - BRPX )	Hysteresis (Note 13)	T <sub>A</sub> = -40°C to +125°C	10	15	22	

Notes:

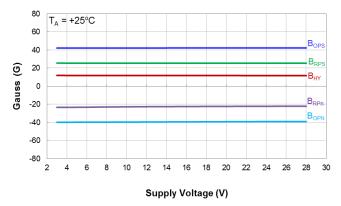
- 11. When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.
- 12. Typical values are defined at  $T_A = +25^{\circ}C$ ,  $V_{DD} = 12V$ . Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.



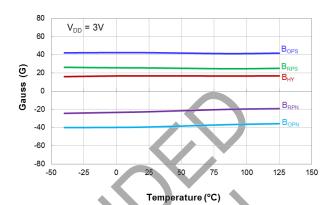


### **Typical Operating Characteristics**

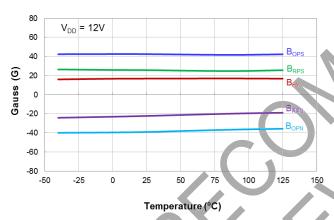
#### Output Switch Operate and Release Points (Magnetic Thresholds) - Bops and BRPs



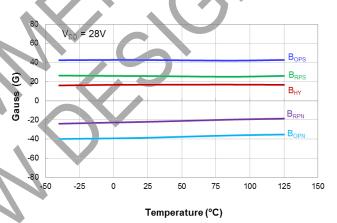
Switch Points  $B_{\text{OPS}}$  and  $B_{\text{RPS}}$  vs Supply Voltage



Switch Points B<sub>OPS</sub> and B<sub>RPS</sub> vs Temperature

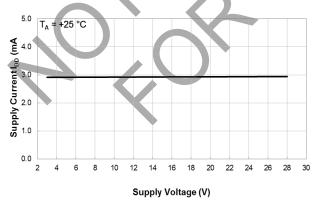


Switch Points B<sub>OPS</sub> and B<sub>RPS</sub> vs Temperature

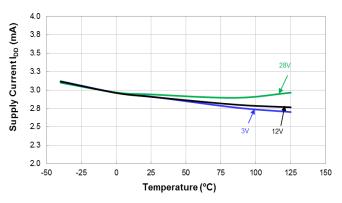


Switch Points  $B_{\text{OPS}}$  and  $B_{\text{RPS}}$  vs Temperature

### **Supply Current**



Supply Current vs Supply Voltage

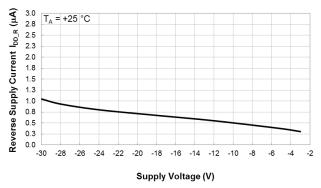


**Supply Current vs Temperature** 

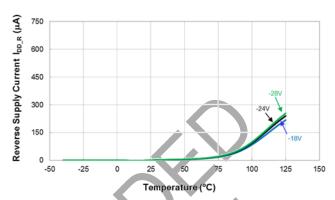


### **Typical Operating Characteristics** (continued)

#### **Supply Reverse Current**

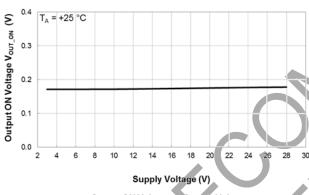


Reverse Supply Current vs Supply Voltage

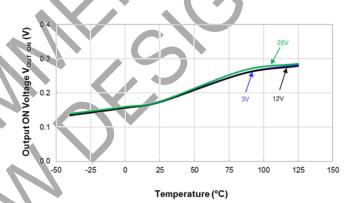


Reverse Supply Current vs Temperature

#### **Output Switch On Voltage**

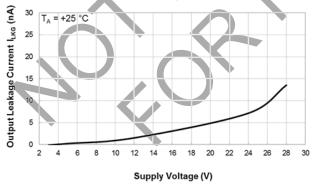


Output ON Voltage vs Supply Voltage

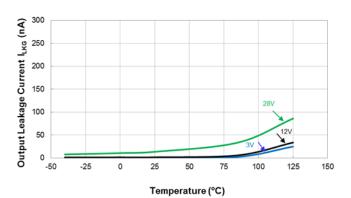


Output ON Voltage vs Temperature

#### **Output Switch Leakage Current**



Output Leakage Current vs Supply Voltage

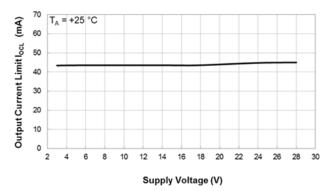


**Output Leakage Current vs Temperature** 

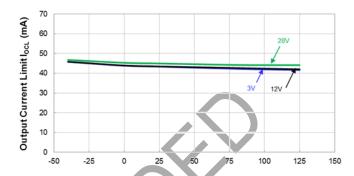


### **Typical Operating Characteristics** (continued)

### **Output Current Limit**



Output Current Limit vs Supply Voltage



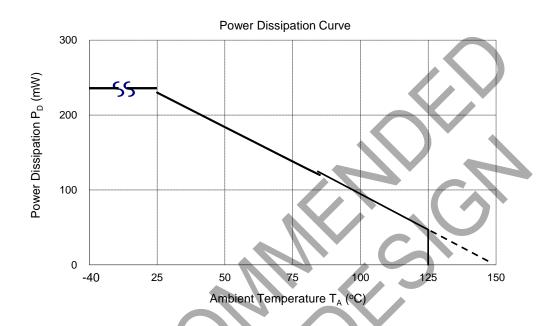
Temperature (°C)
Output CurrentLimit vs Temperature



### **Thermal Performance Characteristics**

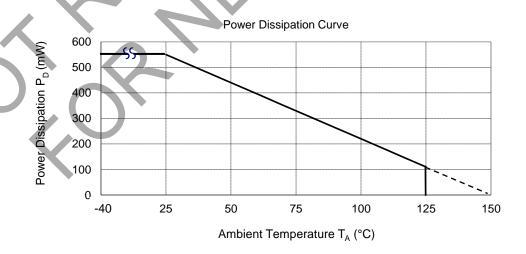
### (1) Package Type: SOT23

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



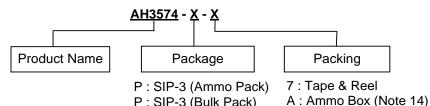
#### (2) Package Types: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





### **Ordering Information**



P: SIP-3 (Bulk Pack) B: Bulk (Note 15) SA: SOT23

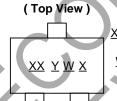
Part Number	Backago Codo	Package	Part Number Suffix	Packing			
Fait Number	Package Code	Fackage	Part Number Sumx	Qty.	Carrier		
AH3574-P-A	Р	SIP-3 (Ammo Pack)	-A	4000	Ammo Box		
AH3574-P-B	Р	SIP-3 (Bulk Pack)	-B	1000	Bulk		
AH3574-SA-7	SA	SOT23	7	3000	7" Tape & Reel		

14. Ammo Box is for SIP-3 (Ammo Pack) Spread Lead. Notes:

15. Bulk is for SIP-3 (Bulk Pack) Straight Lead.

### **Marking Information**

#### (1) Package Type: SOT23



XX: Identification Code

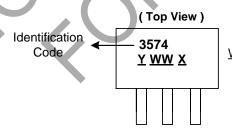
 $\overline{Y}$ : Year 0 to 9 (ex: 3 = 2023)

W: Week: A to Z: week 1 to 26; a to z: week 27 to 52; z represents week 52 and 53

X: Internal Code

Part Number	Package	Identification Code
AH3574-SA-7	SOT23	Z8

### (2) Package Types: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)



 $\underline{Y}$ : Year: 0 to 9 (ex: 3 = 2023)

WW: Week: 01 to 52, "52" represents

week 52 and 53  $\underline{X}$ : Internal Code

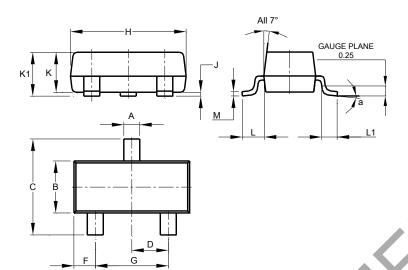
Part Number	Package	Identification Code	
AH3574-P-A	SIP-3 (Ammo Pack)	3574	
AH3574-P-B	SIP-3 (Bulk Pack)	3574	



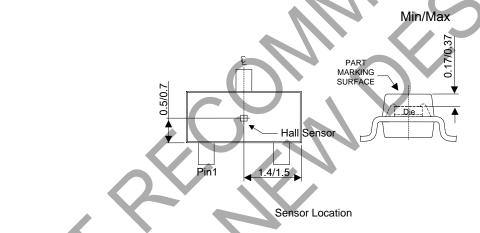
### Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SOT23



	SO	Г23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Η	2.80	3.00	2.90
7	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
Ý	0.45	0.61	0.55
L1	0.25	0.55	0.40
×	0.085	0.150	0.110
a	0°	8°	1
All I	Dimensi	ions in I	mm

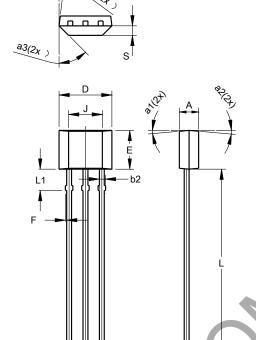




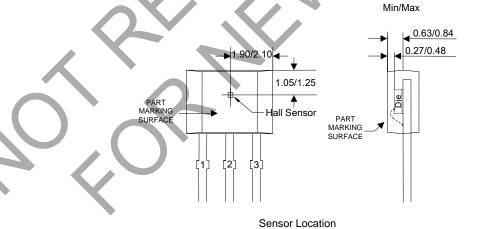
### Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (2) Package Type: SIP-3 (Bulk Pack)



S	IP-3 (Bu	lk Pacl	<b>(</b> )
Dim	Min	Max	Тур
Α	1.40	1.60	1.50
b	0.33	0.43	0.38
b2	0.40	0.508	0.46
С	0.35	0.41	0.38
D	3.90	4.30	4.10
Е	2.80	3.20	3.00
e1	1.24	1.30	1.27
F	0.00	0.20	
J	2	.62 REI	=
L	14.00	15.00	14.50
L1	1.55	1.75	1.65
S	0.63	0.84	0.74
a1			5°
a2			5°
a3		-7	45°
a4			3°
All I	Dimensi	ons in	mm

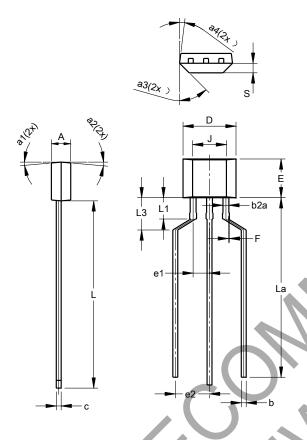




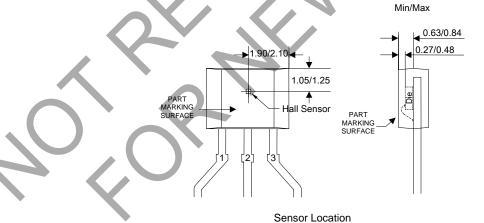
### Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (3) Package Type: SIP-3 (Ammo Pack)



SIP-3				
(Ammo Pack)				
Dim	Min	Max	Тур	
Α	1.40	1.60	1.50	
b	0.33	0.43	0.38	
b2a	0.40	0.52	0.46	
С	0.35	0.41	0.38	
D	3.90	4.30	4.10	
Е	2.80	3.20	3.00	
e1	1.24	1.30	Ĭ.27	
e2	2.40	2.90	2.65	
Ä	0.00	0.20		
7	2.62 REF			
٦	14.00	15.00	14.50	
La	12.90	14.90	13.90	
L1	1.55	1.75	1.65	
L3	2.00	3.00	2.50	
S	0.63	0.84	0.74	
a1	-		5°	
a2		/	5°	
a3	<b>*</b>		45°	
a4			3°	
All Dimensions in mm				

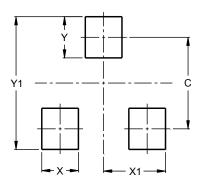




## Suggested Pad Layout

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

Package Type: SOT23



Dimensions	Value (in mm)	
С	2.0	
Х	0.8	
X1	1.35	
Υ	0.9	
Y1	2.9	



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